EAST - [10.681247.wsp:1]

File View Edit Tools Window Help

- Drafts
- Pending
- Active
  - L2: (2) "20030090928"
  - L3: (2) "20030189221"
  - L4: (53829) SRAM or (static adj3 memory)
  - L5: (141518) flip-flop or (flip adj flop)
  - L6: (71290) (channel or well) adj2 region
  - L7: (1251) high adj2 current adj2 drive
  - L8: (160) 5 same 6
  - L9: (0) 7 same 8
  - L10: (0) 7 and 8
  - L11: (2276) 5 and 6
  - L12: (21) 7 and 11
  - L13: (138) high adj2 current adj2 drivability
  - L14: (1406) current adj2 drive adj2 capability
  - L15: (160) 8 and 11
  - L16: (4) 13 and 11
  - L17: (32) 14 and 11
  - L20: (31445) current adj2 (drive or drivability)
  - L21: (218) 11 and 20
  - L22: (168) 21 not (12 or 16 or 17)
  - L23: (94) 4 and 22
  - L24: (3189) 365/154
  - L25: (1398) 365/156
  - L26: (37) 8 and 24
  - L27: (14) 8 and 25
  - L28: (61) 8 and 365/
  - L29: (27) 28 not (26 or 27)
  - L30: (771) 4 same 6
  - L31: (186) 365/ and 30
  - L32: (178) 31 not 23
  - L33: (154) 32 not (26 or 27 or 28)
  - L34: (78) (read adj transistor) same 6
  - L35: (36) 34 and 365/
  - L36: (42) 34 not 35
  - L37: (55) (TAKEMURA near2 TAKASHI).in
- Failed
- Saved

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DBs: USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB — Plurals

Default operator: OR — Highlight all hit terms initially

BRS form | ISAR form | Image | Text | HTML

	U	1	2	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval Cla	Inventor	S	C	P
1		☑		US 5388067 A	19950207	34	Semiconductor memory cell	365/154	257/E27.1; 257/E27.101;		Sato, Nolifumi et al.	☑		

Hits | Details | HTML

Ready — NUM

Start | Cli... | Proxi... | e... | In... | Ex... | D... | IF... | M... | E... | D... | 2:41 PM